

# Shanghai GTO Electronics Co. LTD

## SPECIFICATION SHEET

CUSTOMER		MODEL NO.	IC-LED-GA32R3
SAMPLE DATE		DESCRIPTION	30W Integrated High Power LED

### CUSTOMER AUTHORIZED SIGNATURE

ENGINEERING DEPARTMENT		
APPROVED	CHECKED	PREPARED
Roger Hsu	Peter Chen	Sam Liu

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## Description

### Features.:

- ◆ Super high Flux output and high Luminance
- ◆ Adapt to large current circuit
- ◆ Low thermal resistance:1.2°C/W
- ◆ Wide viewing angle , Integrated
- ◆ RoHS compliant

### Applications.:

- ◆ General Lighting
- ◆ Architectural lighting
- ◆ Decorative lighting
- ◆ Flood lights, cast light lamps
- ◆ Street lamp, tunnel lamp

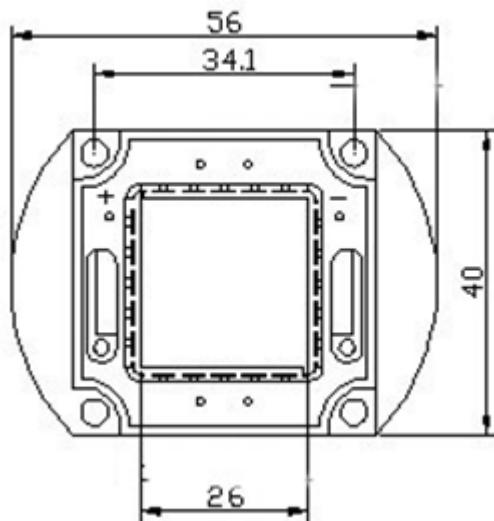
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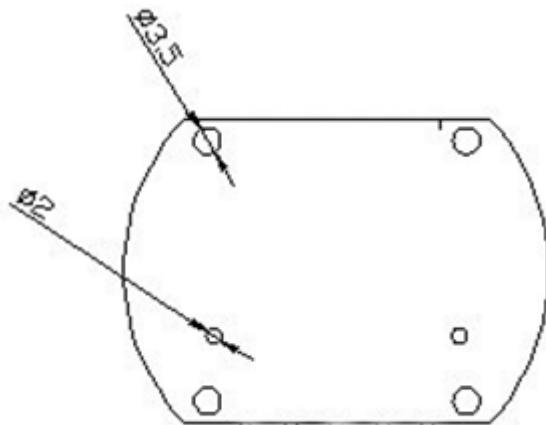
## Outline Dimensions

### 1、 Dome Type



### 2、 Circuit diagram

INTERNAL CIRCUIT  
DIAGRAM



#### Notes:

1. All dimensions are in millimetre (tolerance:  $\pm 0.2$ )
2. Dimension Scale: 1:1

\*The appearance and specifications of the product may be changed for improvement without notice.

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## Parameters

### Electrical-Optical Characteristics at Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit
Luminous Flux	$\phi_v$	2500	~	4000	lm
Wavelength	$\lambda_D$	460	~	470	nm
Forward Voltage	$V_F$	30	~	40	V
Power Dissipation	$P_D$	31.5	~	42	W
View Angle	$2\theta_{1/2}$	~	120	~	deg.
Thermal Resistance	$R_{\theta J-B}$	~	1.2	~	°C/W

### Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Forward Current	$I_F$	1050	mA
Junction Temperature	$T_j$	115	°C
Operating Temperature	$T_{opr}$	-40~+60	°C
Storage Temperature	$T_{stg}$	0~+60	°C
ESD Sensitivity	~	±2,000V HBM	~
Temperature Coefficient of voltage	~	-5	$mV/°C$
DC Pulse Current(@ 1 KHz,10% duty cycle)	$I_{FP}$	1000	mA
Reverse Voltage	$V_R$	Not designed for reverse operation	

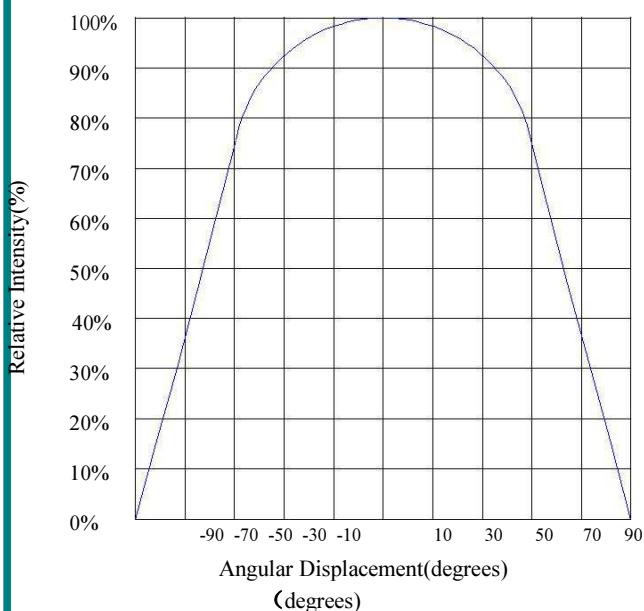
\*Notes:

1. Tolerance of Luminous Flux is ±3%.
2. Tolerance of Forward Voltage is ±0.1V.

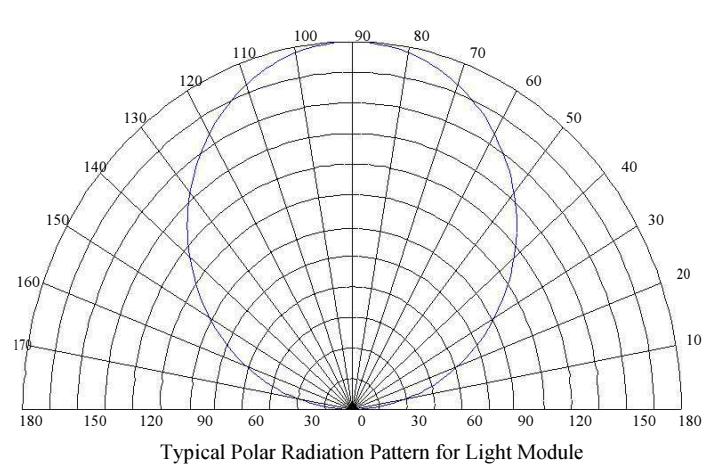
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## Typical Characteristic Curves (1)

### 1.Typical Light Distribution Curve



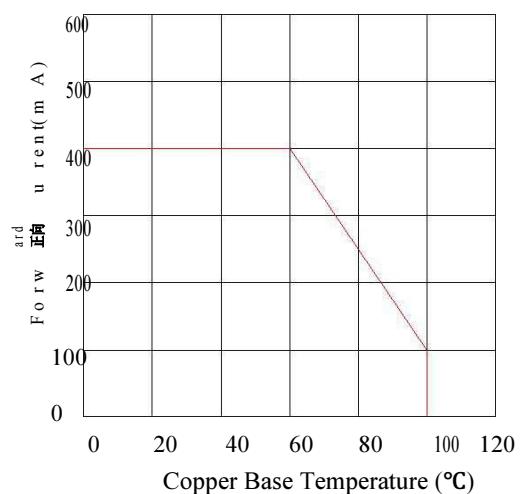
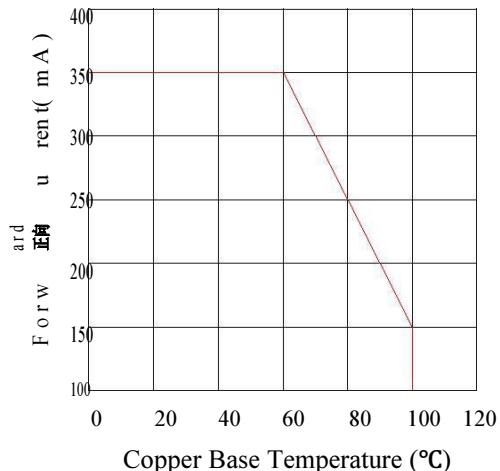
### 2.Typical Light-Emitting Angle Radiation Pattern



### 3. Forward Current Derating Curve, Derating based on $T_{jmax}=115^{\circ}\text{C}$ $T_{jmax}=115^{\circ}\text{C}$

3-1: White,Royal Blue, Blue, Green

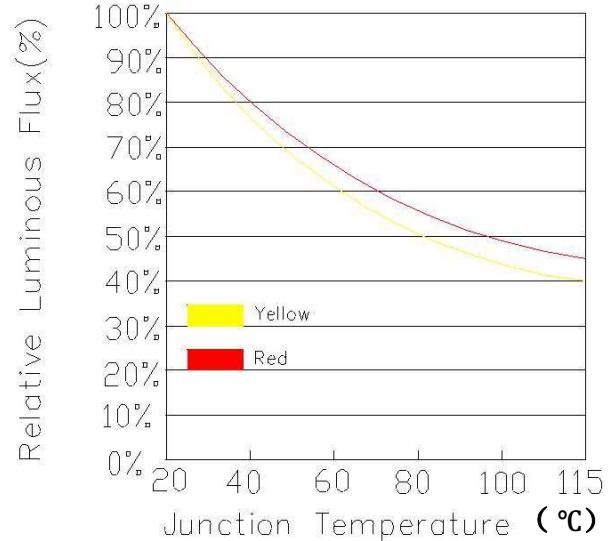
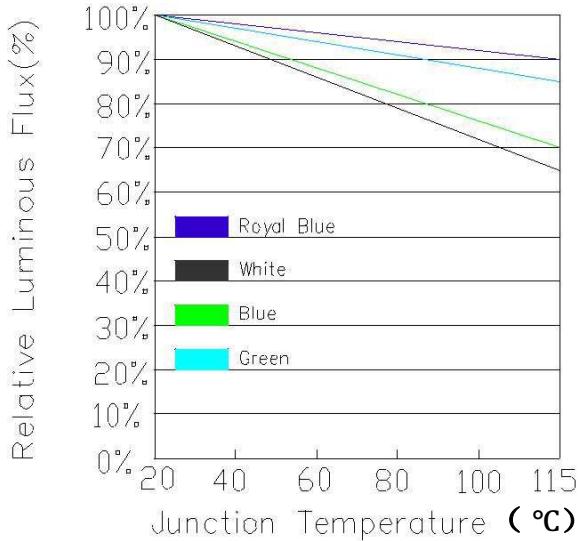
3-2: Amber, Red



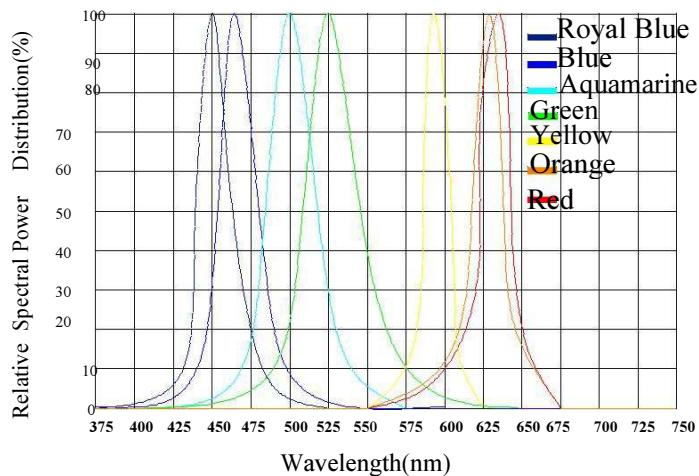
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## Typical Characteristic Curves (2)

4-1. Relative Flux vs. Junction Temperature White, Royal Blue, Blue, Green 4-2.Relative Flux vs. Junction Temperature Amber, Red



## 5.Relative Spectral Power Distribution



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## Reliability Test Items and Conditions

Test Items	Test Condition	Test Hours Cycles	Sample Size	Ac/Re
<b>DC Aging</b>	Ta=25°C IF=1050mA	1000H	22	0/1
<b>Hot and cold shock</b>	-40°C/30min +100°C/30min	100Cycles	22	0/1
<b>High Temperature Storage</b>	Ta=100°C	1000H	22	0/1
<b>High Temperature High Humidity</b>	85°C/85%RH	1000H	22	0/1
<b>Low Temperature Storage</b>	Ta=-40°C	1000H	22	0/1
<b>ESD(HBM)</b>	2000V HBM	1Time	10	0/1

## Criteria For Judging the Damage

Items	Symbol	Test Condition	Criteria For Judging Damage
Forward Voltage	$V_F$	$I_F=1050m$ $A$	Initial Data $\pm 10\%$ $\pm 10\%$
Reverse Current	$I_R$	$V_R=25V$	$I_R \leq 20\mu A$
Luminous Flux	$\phi V$	$I_F=1050m$ $A$	Average $\phi V$ degradation $\leq 30\%$ Single LED $\phi V$ degradation $\leq 50\%$